

UNISONIC TECHNOLOGIES CO., LTD

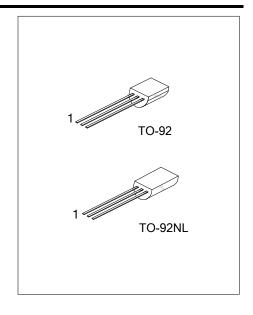
2SB562

PNP EPITAXIAL SILICON TRANSISTOR

LOW FREQUENCY POWER **AMPLIFIER**

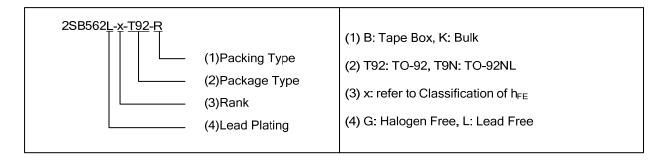
FEATURES

- * Low frequency power amplifier
- * Complement to 2SD468



ORDERING INFORMATION

Order	Order Number		Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
2SB562L-x-T92-B	2SB562G-x-T92-B	TO-92	Е	С	В	Tape Box	
2SB562L-x-T92-K	2SB562G-x-T92-K	TO-92	Е	С	В	Bulk	
2SB562L-x-T9N-B	2SB562G-x-T9N-B	TO-92NL	E	С	В	Tape Box	
2SB562L-x-T9N-K	2SB562G-x-T9N-K	TO-92NL	E	С	В	Bulk	



www.unisonic.com.tw 1 of 4 QW-R211-004.B

■ ABSOLUTE MAXIMUM RATING (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V _{CBO}	-25	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Base Voltage	V _{EBO}	-5	V
Collector Current	lc	-1	А
Collector Peak Current	lc(peak)	-1.5	A
Collector Power Dissipation	Pc	0.9	W
Junction Temperature	TJ	150	°C
Storage Temperature	T _{STG}	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

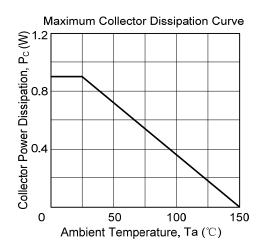
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector to Base Breakdown Voltage	$V_{(BR)CBO}$	Ic=-10μA, I _E =0	-25			V
Collector to Emitter Breakdown Voltage	$V_{(BR)CEO}$	Ic=-1mA, R _{BE} =∞	-20			V
Emitter to Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-10\mu A, I_C=0$	-5			V
Collector Cut-Off Current	I _{CBO}	V_{CB} =-20 V , I_E =0			-1	μΑ
DC Current Transfer Ratio	h_FE	V _{CE} =-2V, Ic=-0.5A (note)	85		240	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	Ic=-0.8A, I _B =-0.08A (note)		-0.2	-0.5	V
Base to Emitter Voltage	V_{BE}	V _{CE} =-2V, Ic=-0.5A (note)		-0.8	-1.0	V
Gain Bandwidth Product	f_{T}	V _{CE} =-2V, Ic=-0.5A (note)		350		MHz
Collector Output Capacitance	C_{ob}	V_{CB} =-10V, I_E =0, f=1MHz		38		pF

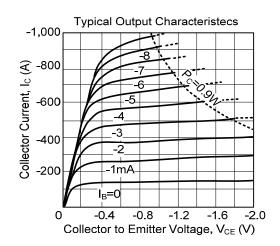
Note 1: Pulse test

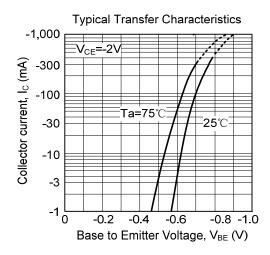
■ CLASSIFICATION OF hFE

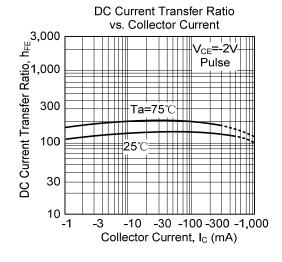
RANK	В	С		
RANGE	85 - 170	120 - 240		

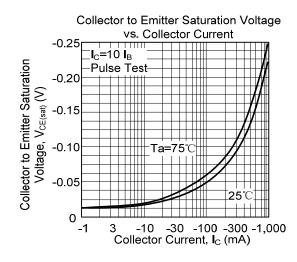
■ TYPICAL CHARACTERISTICS

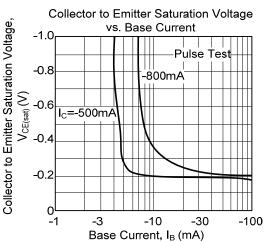




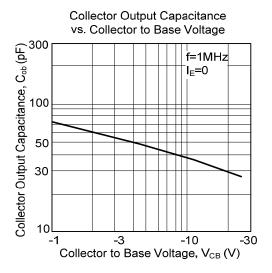








■ TYPICAL CHARACTERISTICS



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